

### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V <sub>DSS</sub>	-20	V
Gate-Source Voltage		V <sub>GSS</sub>	±10	V
Continuous Drain Current, V <sub>GS</sub> = -4.5V (Note 6)	$T_A = +25$ °C $T_C = +25$ °C	ID	-12.7 -42	А
Maximum Continuous Body Diode Forward Current (Note 6)		Is	-3	Α
Pulsed Drain Current (380µs Pulse, Duty Cycle = 1%)		I <sub>DM</sub>	-80	A
Avalanche Current, L=0.1mH (Note 7)		I <sub>AS</sub>	-35	Α
Avalanche Energy, L=0.1mH (Note 7)		E <sub>AS</sub>	64	mJ

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		$P_D$	0.9	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ hetaJA}$	136	°C/W
Total Power Dissipation (Note 6)		$P_{D}$	2.3	W
Thermal Resistance, Junction to Ambient (Note 6)  Steady State		$R_{ hetaJA}$	54	°C/W
Thermal Resistance, Junction to Case (Note 6)		$R_{ heta JC}$	4	C/VV
Operating and Storage Temperature Range		$T_{J_i}T_{STG}$	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

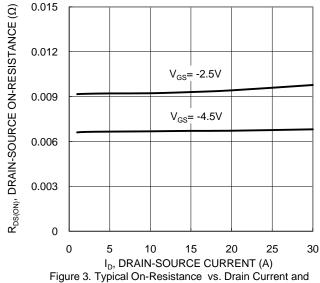
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	_	_	V	$V_{GS} = 0V$ , $I_D = -1mA$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	-1	μA	$V_{DS} = -16V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 8V$ , $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)						•	
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.4	_	-1.2	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance		-	_	9.5	mΩ	$V_{GS} = -4.5V$ , $I_{D} = -3.6A$	
Static Drain-Source Off-Resistance	R <sub>DS(ON)</sub>		_	12.5		$V_{GS} = -2.5V$ , $I_D = -3.6A$	
Diode Forward Voltage	$V_{SD}$	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -10A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C <sub>iss</sub>	_	3350	_		$V_{DS} = -10V, V_{GS} = 0V$ f = 1.0MHz	
Output Capacitance	Coss	-	527	_	pF		
Reverse Transfer Capacitance	C <sub>rss</sub>	_	460	_			
Gate Resistance	$R_{G}$	-	10.7	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V <sub>GS</sub> = -4.5V)	Qg	_	50	_		$V_{DS} = -10V, I_D = -3.6A$	
Total Gate Charge (V <sub>GS</sub> = -10V)	$Q_g$	-	103	_	nC		
Gate-Source Charge	$Q_{gs}$	_	6.0	_	nc nc		
Gate-Drain Charge	$Q_{gd}$	_	14.4	_			
Turn-On Delay Time	t <sub>D(ON)</sub>	_	9.7	_		$V_{DD} = -10V$ , $V_{GS} = -4.5V$ , $R_{GEN} = 4.7\Omega$ , $I_{D} = -3.6A$	
Turn-On Rise Time	t <sub>R</sub>	_	30	_			
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	235	_	ns		
Turn-Off Fall Time	t <sub>F</sub>	_	110	_	1		
Reverse Recovery Time	t <sub>RR</sub>	_	64	_	ns	1 2 0 4:/-# 400 4/	
Reverse Recovery Charge	$Q_{RR}$		60	_	nC	$I_F = -3.6A$ , di/dt = 100A/ $\mu$ s	

Notes:

- Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
   Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
   I<sub>AS</sub> and E<sub>AS</sub> ratings are based on low frequency and duty cycles to keep T<sub>J</sub> = +25°C.
   Short duration pulse test used to minimize self-heating effect.
   Guaranteed by design. Not subject to product testing.



### 30.0 V<sub>GS</sub>= -2.0V 25.0 V<sub>GS</sub>= -2.5V ID, DRAIN CURRENT (A) 20.0 <sub>GS</sub>= -3.0V V<sub>GS</sub>= -4.0V 15.0 V<sub>GS</sub>= -4.5V 10.0 $V_{GS} = -1.5V$ 5.0 $V_{GS} = -1.2V$ 0.0 0.5 2 0 1.5 V<sub>DS</sub>, DRAIN-SOURCE VOLTAGE (V) Figure 1. Typical Output Characteristic



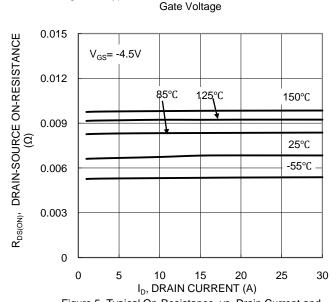
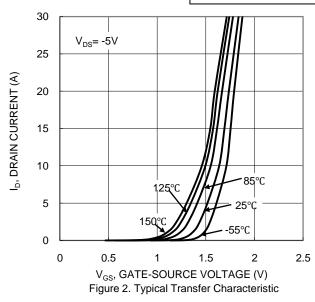


Figure 5. Typical On-Resistance vs. Drain Current and Junction Temperature

# DMP2010UFG



0.02  $R_{DS(ON)}, \, DRAIN-SOURCE \, ON-RESISTANCE \eqno(\Omega)$ 0.018 0.016 0.014 0.012 0.01  $I_{D} = -3.6A$ 0.008 0.006 0.004 0.002 0 0 2 10 V<sub>GS</sub>, GATE-SOURCE VOLTAGE (V) Figure 4. Typical Transfer Characteristic

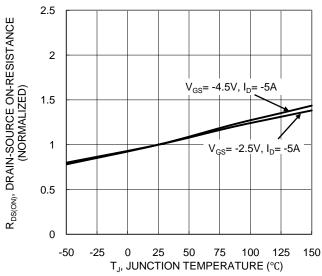
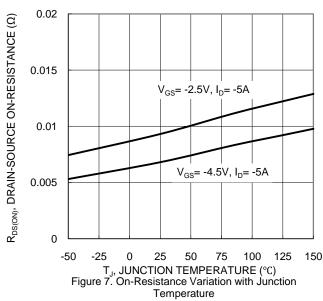
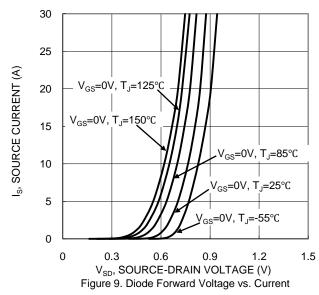
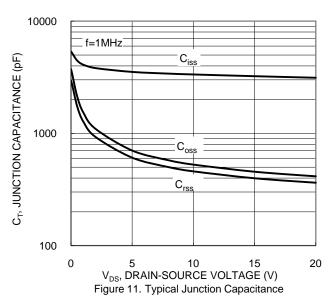
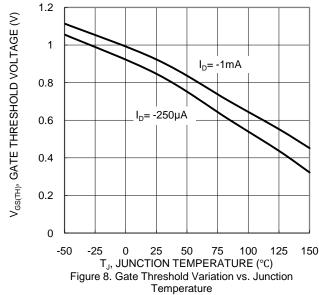


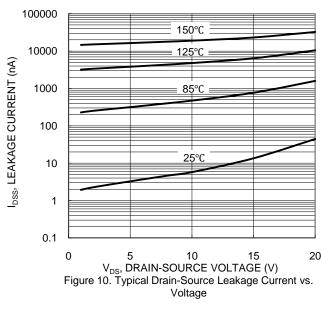
Figure 6. On-Resistance Variation with Junction Temperature

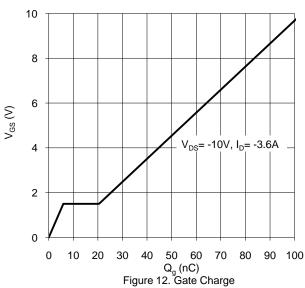




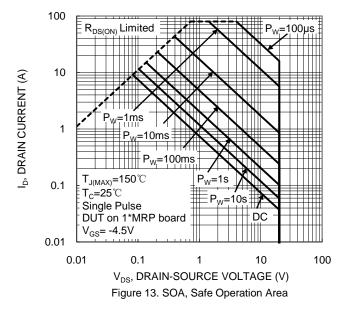












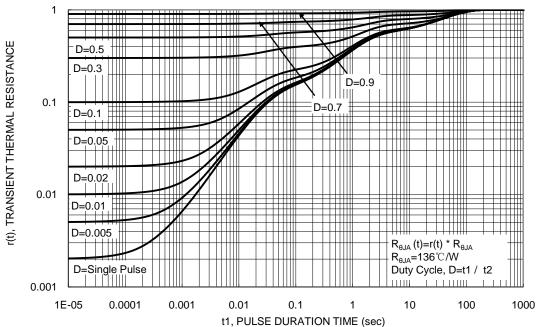
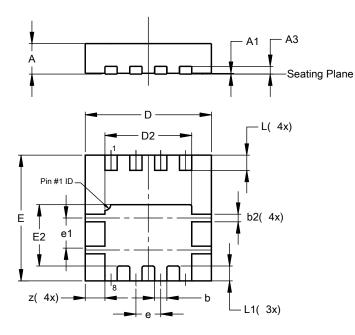


Figure 14. Transient Thermal Resistance



## **Package Outline Dimensions**

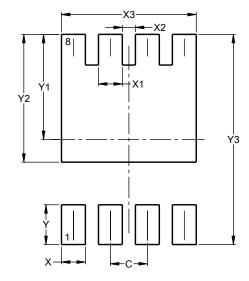
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



POWERDI®3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
А3	_	_	0.203		
b	0.27	0.37	0.32		
b2	_	_	0.20		
D	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
Е	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
е	-	-	0.65		
e1	0.79	0.89	0.84		
L	0.35	0.45	0.40		
L1	_	_	0.39		
Z	_	_	0.515		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
Х3	2.370
Υ	0.700
Y1	1.850
Y2	2.250
V3	3 700



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